

Cammy R Abernathy

List of Publications by Year in descending order

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13
papers

525
citations

1163117

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1372567

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all docs

13
docs citations

13
times ranked

362
citing authors

#	ARTICLE	IF	CITATIONS
1	Indication of ferromagnetism in molecular-beam-epitaxy-derived N-type GaMnN. Applied Physics Letters, 2001, 79, 1312-1314.	3.3	268
2	Production of single phase chalcopyrite CuInSe ₂ by spray pyrolysis. Applied Physics Letters, 1984, 45, 890-892.	3.3	72
3	300°C GaN/AlGa _N Heterojunction Bipolar Transistor. MRS Internet Journal of Nitride Semiconductor Research, 1998, 3, 1.	1.0	70
4	Magnetic properties of P-type GaMnP grown by molecular-beam epitaxy. Applied Physics Letters, 2001, 79, 3128-3130.	3.3	45
5	Effect of pH on the production of chalcopyrite CuInSe ₂ prepared by spray pyrolysis. Applied Physics Letters, 1983, 43, 851-852.	3.3	22
6	New plasma chemistries for etching GaN and InN: BI ₃ and BBr ₃ . MRS Internet Journal of Nitride Semiconductor Research, 1998, 3, 1.	1.0	17
7	Kinetic effects in film formation of CuInSe ₂ prepared by chemical spray pyrolysis. Thin Solid Films, 1984, 115, L41-L43.	1.8	16
8	Defect Trapping and Annealing for Transition Metal Implants in Group III Nitrides. MRS Internet Journal of Nitride Semiconductor Research, 2000, 5, 1.	1.0	9
9	Epitaxial Growth of Dilute Magnetic Semiconductors: GaMnN and GaMnP. Materials Research Society Symposia Proceedings, 2001, 674, 1.	0.1	3
10	Ferromagnetic and Paramagnetic Semiconductors Based upon GaN, AlGa _N , and GaP. Materials Research Society Symposia Proceedings, 2001, 690, F1.5.1.	0.1	2
11	DILUTE MAGNETIC GaN, SiC AND RELATED SEMICONDUCTORS. , 2003, , 477-510.		1
12	Optimization of Samarium Oxide Deposition on Gallium Arsenide. Materials Research Society Symposia Proceedings, 2008, 1108, 1.	0.1	0
13	FABRICATION AND PERFORMANCE OF GaN MOSFETs AND MOSHFETs. , 2003, , 217-259.		0